

Cedric J Powell

List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/1911815/publications.pdf>

Version: 2024-02-01

159
papers

14,529
citations

36203

51
h-index

19136

118
g-index

169
all docs

169
docs citations

169
times ranked

9810
citing authors

#	ARTICLE	IF	CITATIONS
1	Calculations of electron inelastic mean free paths. V. Data for 14 organic compounds over the 50-2000 eV range. <i>Surface and Interface Analysis</i> , 1994, 21, 165-176.	0.8	2,216
2	Calculations of electron inelastic mean free paths. II. Data for 27 elements over the 50-2000 eV range. <i>Surface and Interface Analysis</i> , 1991, 17, 911-926.	0.8	1,161
3	Calculations of electron inelastic mean free paths for 31 materials. <i>Surface and Interface Analysis</i> , 1988, 11, 577-589.	0.8	903
4	Calculations of electron inelastic mean free paths. IX. Data for 41 elemental solids over the 50 eV to 30 keV range. <i>Surface and Interface Analysis</i> , 2011, 43, 689-713.	0.8	746
5	Calculations of electron inelastic mean free paths. III. Data for 15 inorganic compounds over the 50-2000 eV range. <i>Surface and Interface Analysis</i> , 1991, 17, 927-939.	0.8	624
6	Dirac partial-wave calculation of elastic scattering of electrons and positrons by atoms, positive ions and molecules. <i>Computer Physics Communications</i> , 2005, 165, 157-190.	3.0	507
7	Evaluation of Calculated and Measured Electron Inelastic Mean Free Paths Near Solid Surfaces. <i>Journal of Physical and Chemical Reference Data</i> , 1999, 28, 19-62.	1.9	465
8	Calculation of electron inelastic mean free paths (IMFPs) VII. Reliability of the TPP-2M IMFP predictive equation. <i>Surface and Interface Analysis</i> , 2003, 35, 268-275.	0.8	403
9	Calculations of electron inelastic mean free paths (IMFPs). IV. Evaluation of calculated IMFPs and of the predictive IMFP formula TPP-2 for electron energies between 50 and 2000 eV. <i>Surface and Interface Analysis</i> , 1993, 20, 77-89.	0.8	397
10	Origin of the Characteristic Electron Energy Losses in Aluminum. <i>Physical Review</i> , 1959, 115, 869-875.	2.7	357
11	Cross sections for ionization of inner-shell electrons by electrons. <i>Reviews of Modern Physics</i> , 1976, 48, 33-47.	16.4	354
12	Calculations of electron inelastic mean free paths. X. Data for 41 elemental solids over the 50 eV to 200 keV range with the relativistic full Penn algorithm. <i>Surface and Interface Analysis</i> , 2015, 47, 871-888.	0.8	270
13	Simulation of electron spectra for surface analysis (SESSA): a novel software tool for quantitative Auger-electron spectroscopy and X-ray photoelectron spectroscopy. <i>Surface and Interface Analysis</i> , 2005, 37, 1059-1067.	0.8	233
14	Precision, accuracy, and uncertainty in quantitative surface analyses by Auger-electron spectroscopy and X-ray photoelectron spectroscopy. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1990, 8, 735-763.	0.9	232
15	Effect of Oxidation on the Characteristic Loss Spectra of Aluminum and Magnesium. <i>Physical Review</i> , 1960, 118, 640-643.	2.7	210
16	Calculations of electron inelastic mean free paths. <i>Surface and Interface Analysis</i> , 2005, 37, 1-14.	0.8	210
17	Comparison of Electron Elastic-Scattering Cross Sections Calculated from Two Commonly Used Atomic Potentials. <i>Journal of Physical and Chemical Reference Data</i> , 2004, 33, 409-451.	1.9	204
18	Oxygen as a surfactant in the growth of giant magnetoresistance spin valves. <i>Journal of Applied Physics</i> , 1997, 82, 6142-6151.	1.1	193

#	ARTICLE	IF	CITATIONS
19	Contrasting Valence-Band Auger-Electron Spectra for Silver and Aluminum. <i>Physical Review Letters</i> , 1973, 30, 1179-1182.	2.9	157
20	Characteristic Energy Losses of 8-keV Electrons in Liquid Al, Bi, In, Ga, Hg, and Au. <i>Physical Review</i> , 1968, 175, 972-982.	2.7	141
21	Practical guides for x-ray photoelectron spectroscopy: First steps in planning, conducting, and reporting XPS measurements. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2019, 37, .	0.9	137
22	Relationships between electron inelastic mean free paths, effective attenuation lengths, and mean escape depths. <i>Journal of Electron Spectroscopy and Related Phenomena</i> , 1999, 100, 137-160.	0.8	136
23	Cross Sections for Inner-Shell Ionization by Electron Impact. <i>Journal of Physical and Chemical Reference Data</i> , 2014, 43, .	1.9	133
24	Experimental determination of electron inelastic mean free paths in 13 elemental solids in the 50 to 5000 eV energy range by elastic-peak electron spectroscopy. <i>Surface and Interface Analysis</i> , 2005, 37, 833-845.	0.8	132
25	Magnetoresistance values exceeding 21% in symmetric spin valves. <i>Journal of Applied Physics</i> , 1995, 78, 273-277.	1.1	127
26	Origin of the Characteristic Electron Energy Losses in Magnesium. <i>Physical Review</i> , 1959, 116, 81-83.	2.7	109
27	Formalism and parameters for quantitative surface analysis by Auger electron spectroscopy and x-ray photoelectron spectroscopy. <i>Surface and Interface Analysis</i> , 1993, 20, 771-786.	0.8	102
28	Electron effective attenuation lengths for applications in Auger electron spectroscopy and x-ray photoelectron spectroscopy. <i>Surface and Interface Analysis</i> , 2002, 33, 211-229.	0.8	101
29	Cross sections for ionization of K, L and M shells of atoms by impact of electrons and positrons with energies up to 1GeV: Analytical formulas. <i>Atomic Data and Nuclear Data Tables</i> , 2009, 95, 871-909.	0.9	98
30	Practical expressions for the mean escape depth, the information depth, and the effective attenuation length in Auger-electron spectroscopy and x-ray photoelectron spectroscopy. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2009, 27, 253-261.	0.9	96
31	Calculations of electron inelastic mean free paths. XII. Data for 42 inorganic compounds over the 50 eV to 200 keV range with the full Penn algorithm. <i>Surface and Interface Analysis</i> , 2019, 51, 427-457.	0.8	92
32	Calculations of Electron Inelastic Mean Free Paths (IMFPs)VI. Analysis of the Gries Inelastic Scattering Model and Predictive IMFP Equation. <i>Surface and Interface Analysis</i> , 1997, 25, 25-35.	0.8	90
33	Calculations of electron inelastic mean free paths. XI. Data for liquid water for energies from 50 eV to 30 keV. <i>Surface and Interface Analysis</i> , 2017, 49, 238-252.	0.8	82
34	Energy and material dependence of the inelastic mean free path of low-energy electrons in solids. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1985, 3, 1338-1342.	0.9	79
35	Practical guide for inelastic mean free paths, effective attenuation lengths, mean escape depths, and information depths in x-ray photoelectron spectroscopy. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2020, 38, .	0.9	77
36	Optimizing the giant magnetoresistance of symmetric and bottom spin valves (invited). <i>Journal of Applied Physics</i> , 1996, 79, 5277.	1.1	75

#	ARTICLE	IF	CITATIONS
37	Information depth and the mean escape depth in Auger electron spectroscopy and x-ray photoelectron spectroscopy. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2003, 21, 274-283.	0.9	74
38	Summary Abstract: Accurate determination of the energies of Auger electrons and photoelectrons from nickel, copper, and gold. <i>Journal of Vacuum Science and Technology</i> , 1982, 20, 625-625.	1.9	73
39	Growth of giant magnetoresistance spin valves using indium as a surfactant. <i>Journal of Applied Physics</i> , 1996, 79, 2491-2496.	1.1	72
40	Artifacts in ballistic magnetoresistance measurements (invited). <i>Journal of Applied Physics</i> , 2004, 95, 7554-7559.	1.1	69
41	Inelastic Scattering Cross Sections for 20-keV Electrons in Al, Be, and Polystyrene. <i>Physical Review</i> , 1966, 145, 195-208.	2.7	66
42	Mean escape depth of signal photoelectrons from amorphous and polycrystalline solids. <i>Physical Review B</i> , 1996, 54, 10927-10937.	1.1	64
43	Evaluation of electron inelastic mean free paths for selected elements and compounds. <i>Surface and Interface Analysis</i> , 2000, 29, 108-114.	0.8	62
44	Growth of giant magnetoresistance spin valves using Pb and Au as surfactants. <i>Journal of Applied Physics</i> , 1996, 80, 5183-5191.	1.1	61
45	Calculations of stopping powers of 100 eV to 30 keV electrons in 10 elemental solids. <i>Surface and Interface Analysis</i> , 2005, 37, 978-988.	0.8	60
46	The energy dependence of electron attenuation lengths. <i>Surface and Interface Analysis</i> , 1985, 7, 256-262.	0.8	59
47	Proliferation of Faulty Materials Data Analysis in the Literature. <i>Microscopy and Microanalysis</i> , 2020, 26, 1-2.	0.2	59
48	Energy calibration of x-ray photoelectron spectrometers: Results of an interlaboratory comparison to evaluate a proposed calibration procedure. <i>Surface and Interface Analysis</i> , 1995, 23, 121-132.	0.8	55
49	Elastic-electron-scattering effects on angular distributions in x-ray-photoelectron spectroscopy. <i>Physical Review B</i> , 1994, 50, 4739-4748.	1.1	54
50	Plasmon Damping in Metals. <i>Physical Review</i> , 1966, 145, 209-217.	2.7	52
51	Standard test data for estimating peak parameter errors in x-ray photoelectron spectroscopy III. Errors with different curve-fitting approaches. <i>Surface and Interface Analysis</i> , 2000, 29, 856-872.	0.8	52
52	Calculations of electron inelastic mean free paths from experimental optical data. <i>Surface and Interface Analysis</i> , 1985, 7, 263-274.	0.8	49
53	Evaluation of correction parameters for elastic-scattering effects in x-ray photoelectron spectroscopy and Auger electron spectroscopy. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1997, 15, 2095-2106.	0.9	47
54	Excitation of π Electrons in Polystyrene and Similar Polymers by 20-keV Electrons. <i>Journal of Chemical Physics</i> , 1963, 39, 630-634.	1.2	46

#	ARTICLE	IF	CITATIONS
55	Attenuation lengths of low-energy electrons in solids derived from the yield of proton-excited Auger electrons: beryllium and aluminum. <i>Physical Review B</i> , 1977, 16, 1370-1379.	1.1	45
56	Calculations of stopping powers of 100eV–30keV electrons in 31 elemental solids. <i>Journal of Applied Physics</i> , 2008, 103, .	1.1	45
57	NIST databases with electron elastic-scattering cross sections, inelastic mean free paths, and effective attenuation lengths. <i>Surface and Interface Analysis</i> , 2005, 37, 1068-1071.	0.8	44
58	Effects of Contamination on the Characteristic Loss Spectrum of Tungsten. <i>Physical Review</i> , 1958, 110, 657-660.	2.7	43
59	Evaluating the Internal Structure of Core-Shell Nanoparticles Using X-ray Photoelectron Intensities and Simulated Spectra. <i>Journal of Physical Chemistry C</i> , 2015, 119, 17687-17696.	1.5	41
60	Monte Carlo strategies for simulations of electron backscattering from surfaces. <i>Surface and Interface Analysis</i> , 2005, 37, 861-874.	0.8	39
61	New universal expression for the electron stopping power for energies between 200 eV and 30 keV. <i>Surface and Interface Analysis</i> , 2006, 38, 76-83.	0.8	39
62	Innershell Ionization Cross Sections. , 1985, , 198-231.		39
63	Surface oxidation as a diffusion barrier for Al deposited on ferromagnetic metals. <i>Journal of Applied Physics</i> , 2001, 89, 5209-5214.	1.1	34
64	Influence of elastic-electron scattering on measurements of silicon dioxide film thicknesses by x-ray photoelectron spectroscopy. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2001, 19, 2604-2611.	0.9	34
65	Excitation of L-Shell Electrons in Al and Al ₂ O ₃ by 20-keV Electrons. <i>Physical Review</i> , 1968, 167, 592-600.	2.7	33
66	L ₃ VV Auger-Electron Line Shapes and Peak Positions for Near-Threshold Electron Excitation in Nickel and Copper. <i>Physical Review Letters</i> , 1981, 46, 953-956.	2.9	33
67	Interpretation of nanoparticle X-ray photoelectron intensities. <i>Applied Physics Letters</i> , 2014, 104, .	1.5	33
68	Growth and trends in Auger-electron spectroscopy and x-ray photoelectron spectroscopy for surface analysis. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2003, 21, S42-S53.	0.9	31
69	Quantitative interpretation of molecular dynamics simulations for X-ray photoelectron spectroscopy of aqueous solutions. <i>Journal of Chemical Physics</i> , 2016, 144, 154704.	1.2	31
70	High-Resolution Measurements of the L ₃ M _{2,3} M _{4,5} Auger Transitions in Nickel and Copper. <i>Physical Review Letters</i> , 1972, 29, 1153-1156.	2.9	30
71	Recent developments in quantitative surface analysis by electron spectroscopy. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1986, 4, 1532-1539.	0.9	30
72	Improved algorithm for calculating transport cross sections of electrons with energies from $\int_0^{50} \frac{d\sigma}{dE} dE$ to $\int_0^{30} \frac{d\sigma}{dE} dE$. <i>Physical Review B</i> , 2007, 76, .	1.1	30

#	ARTICLE	IF	CITATIONS
73	Effective Attenuation Lengths for Different Quantitative Applications of X-ray Photoelectron Spectroscopy. <i>Journal of Physical and Chemical Reference Data</i> , 2020, 49, .	1.9	30
74	Comparisons of calculated and measured effective attenuation lengths for silicon dioxide over a wide electron energy range. <i>Surface Science</i> , 2001, 488, L547-L552.	0.8	29
75	Development of the web-based NIST X-ray Photoelectron Spectroscopy (XPS) Database. <i>Data Science Journal</i> , 2002, 1, 1-12.	0.6	28
76	Comparisons of Analytical Approaches for Determining Shell Thicknesses of Core-Shell Nanoparticles by X-ray Photoelectron Spectroscopy. <i>Journal of Physical Chemistry C</i> , 2018, 122, 4073-4082.	1.5	28
77	The energy dependence of electron inelastic mean free paths. <i>Surface and Interface Analysis</i> , 1987, 10, 349-354.	0.8	27
78	Growth of Surface Analysis and the Development of Databases and Modeling Software for Auger-Electron Spectroscopy and X-ray Photoelectron Spectroscopy. <i>Microscopy Today</i> , 2016, 24, 16-23.	0.2	26
79	Thin Al, Au, Cu, Ni, Fe, and Ta films as oxidation barriers for Co in air. <i>Journal of Applied Physics</i> , 2003, 93, 8731-8733.	1.1	24
80	Modified predictive formula for the electron stopping power. <i>Journal of Applied Physics</i> , 2008, 103, .	1.1	24
81	The development of standards for surface analysis. <i>Surface and Interface Analysis</i> , 1988, 11, 103-109.	0.8	23
82	Standard test data for estimating peak-parameter errors in x-ray photoelectron spectroscopy. I. Peak binding energies. <i>Surface and Interface Analysis</i> , 1998, 26, 939-956.	0.8	23
83	Hot-electron attenuation lengths in ultrathin magnetic films. <i>Journal of Applied Physics</i> , 2000, 87, 5164-5166.	1.1	23
84	Differences in the Characteristic Electron Energy-Loss Spectra of Solid and Liquid Bismuth. <i>Physical Review Letters</i> , 1965, 15, 852-854.	2.9	22
85	Large Final-State Effects in the Core-Level Electron Energy-Loss Spectra of Vanadium at Low Incident-Electron Energies. <i>Physical Review Letters</i> , 1983, 51, 61-64.	2.9	22
86	Simulation of Electron Spectra for Surface Analysis (SESSA) for quantitative interpretation of (hard) X-ray photoelectron spectra (HAXPES). <i>Journal of Electron Spectroscopy and Related Phenomena</i> , 2013, 190, 137-143.	0.8	22
87	Effective attenuation lengths for quantitative determination of surface composition by Auger-electron spectroscopy and X-ray photoelectron spectroscopy. <i>Journal of Electron Spectroscopy and Related Phenomena</i> , 2017, 218, 1-12.	0.8	22
88	Inelastic Scattering of Kilovolt Electrons by Solids and Liquids. <i>Health Physics</i> , 1967, 13, 1265-1276.	0.3	21
89	High-Resolution Measurements of Auger-Electron and Photoelectron Structure in the Secondary-Electron Energy Distributions of Aluminum, Nickel, and Copper. <i>Physical Review B</i> , 1972, 6, 4418-4429.	1.1	21
90	Distinguishability of N composition profiles in SiON films on Si by angle-resolved x-ray photoelectron spectroscopy. <i>Applied Physics Letters</i> , 2006, 89, 172101.	1.5	21

#	ARTICLE	IF	CITATIONS
91	Evaluation of Two Methods for Determining Shell Thicknesses of Core-Shell Nanoparticles by X-ray Photoelectron Spectroscopy. <i>Journal of Physical Chemistry C</i> , 2016, 120, 22730-22738.	1.5	20
92	Calculations of electron inelastic mean free paths. XIII. Data for 14 organic compounds and water over the 50 eV to 200 keV range with the relativistic full Penn algorithm. <i>Surface and Interface Analysis</i> , 2022, 54, 534-560.	0.8	20
93	Consistency of calculated and measured electron inelastic mean free paths. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1999, 17, 1122-1126.	0.9	19
94	Effect of backscattered electrons on the analysis area in scanning Auger microscopy. <i>Applied Surface Science</i> , 2004, 230, 327-333.	3.1	19
95	Suppression of orange-peel coupling in magnetic tunnel junctions by preoxidation. <i>Applied Physics Letters</i> , 2006, 88, 162508.	1.5	19
96	Sample-morphology effects on x-ray photoelectron peak intensities. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2013, 31, .	0.9	18
97	Formal databases for surface analysis: The current situation and future trends. <i>Surface and Interface Analysis</i> , 1991, 17, 308-314.	0.8	17
98	Recommended Auger-electron kinetic energies for 42 elemental solids. <i>Journal of Electron Spectroscopy and Related Phenomena</i> , 2010, 182, 11-18.	0.8	17
99	Determination of the Be Auger electron attenuation length in Be using 160 keV protons. <i>Applied Physics Letters</i> , 1977, 30, 357-359.	1.5	16
100	Surface chemical analysis report on the vamas project. <i>Surface and Interface Analysis</i> , 1986, 9, 79-83.	0.8	16
101	Low-temperature growth of giant magnetoresistance spin valves. <i>Journal of Applied Physics</i> , 1996, 79, 282-290.	1.1	16
102	Characterization of the imaging properties of a double-pass cylindrical-mirror analyzer. <i>Surface and Interface Analysis</i> , 1986, 9, 111-117.	0.8	15
103	The trade-off between large magnetoresistance and small coercivity in symmetric spin valves. <i>Journal of Applied Physics</i> , 1996, 79, 8603-8606.	1.1	15
104	Evaluation of uncertainties in X-ray photoelectron spectroscopy intensities associated with different methods and procedures for background subtraction. I. Spectra for monochromatic Al X-ray. <i>Surface and Interface Analysis</i> , 2009, 41, 269-294.	0.8	15
105	elsevier Dirac partial-wave calculation of elastic scattering of electrons and positrons by atoms, positive ions and molecules (New Version Announcement). <i>Computer Physics Communications</i> , 2021, 261, 107704.	3.0	15
106	Progress of the ASTM E-42 committee on surface analysis. <i>Surface and Interface Analysis</i> , 1981, 3, 94-98.	0.8	14
107	The status of reference data, reference materials and reference procedures in surface analysis. <i>Surface and Interface Analysis</i> , 1988, 13, 46-50.	0.8	14
108	Experimental determination of electron effective attenuation lengths in silicon dioxide thin films using synchrotron radiation I. Data analysis and comparisons. <i>Surface and Interface Analysis</i> , 2000, 29, 330-335.	0.8	14

#	ARTICLE	IF	CITATIONS
109	Refined calculations of effective attenuation lengths for SiO ₂ film thicknesses by x-ray photoelectron spectroscopy. <i>Applied Physics Letters</i> , 2006, 89, 252116.	1.5	14
110	Structure on the High-Energy Side of the KL23M Auger Peak from Solid Aluminum: Internal Photoemission. <i>Applied Physics Letters</i> , 1972, 20, 335-337.	1.5	13
111	Standard test data for estimating peak parameter errors in x-ray photoelectron spectroscopy: II. Peak intensities. <i>Surface and Interface Analysis</i> , 2000, 29, 444-459.	0.8	13
112	Intermixing of aluminum-magnetic transition-metal bilayers. <i>Journal of Applied Physics</i> , 2003, 93, 8044-8046.	1.1	13
113	Improvements in the Reliability of X-ray Photoelectron Spectroscopy for Surface Analysis. <i>Journal of Chemical Education</i> , 2004, 81, 1734.	1.1	13
114	Effective attenuation lengths for photoelectrons in thin films of silicon oxynitride and hafnium oxynitride on silicon. <i>Surface and Interface Analysis</i> , 2013, 45, 628-638.	0.8	12
115	Imaging properties and energy aberrations of a double-pass cylindrical-mirror electron energy analyzer. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1986, 4, 1551-1556.	0.9	11
116	Development of standards for surface analysis by ISO technical committee 201 on surface chemical analysis. <i>Surface and Interface Analysis</i> , 1997, 25, 860-868.	0.8	11
117	Energy calibration of X-ray photoelectron spectrometers. Part III: Location of the zero point on the binding-energy scale. <i>Surface and Interface Analysis</i> , 1998, 26, 606-614.	0.8	11
118	Experimental determination of electron effective attenuation lengths in silicon dioxide thin films using synchrotron radiation II. Effects of elastic scattering. <i>Surface and Interface Analysis</i> , 2000, 29, 336-340.	0.8	11
119	Summary of ISO/TC 201 Standard: XXIX. ISO 20903: 2006 "Surface chemical analysis" Auger electron spectroscopy and X-ray photoelectron spectroscopy methods used to determine peak intensities and information required when reporting results. <i>Surface and Interface Analysis</i> , 2007, 39, 464-466.	0.8	11
120	Effects of elastic scattering and analyzer acceptance angle on the analysis of angle-resolved X-ray photoelectron spectroscopy data. <i>Surface and Interface Analysis</i> , 2011, 43, 1046-1056.	0.8	11
121	Sample-morphology effects on x-ray photoelectron peak intensities. II. Estimation of detection limits for thin-film materials. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2014, 32, .	0.9	11
122	Development of standards for reliable surface analyses by ISO technical committee 201 on surface chemical analysis. <i>Surface and Interface Analysis</i> , 2015, 47, 127-134.	0.8	11
123	Variation of the threshold energies for core-electron excitation in electron energy-loss spectra as a function of incident electron energy. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1983, 1, 1165-1168.	0.9	10
124	Dependence of calculated electron effective attenuation lengths on transport mean free paths obtained from two atomic potentials. <i>Surface and Interface Analysis</i> , 2006, 38, 1348-1356.	0.8	10
125	New Data Resources and Applications for AES and XPS. <i>Journal of Surface Analysis (Online)</i> , 2014, 20, 155-160.	0.1	10
126	Energy transfers in the quasielastic scattering of 70-1250-eV electrons by surfaces. <i>Physical Review B</i> , 1989, 40, 7284-7287.	1.1	9

#	ARTICLE	IF	CITATIONS
127	Formation of Technical Committee 201 on Surface Chemical Analysis by the International Organization for Standardization. <i>Surface and Interface Analysis</i> , 1993, 20, 322-325.	0.8	9
128	Interface intermixing and in-plane grain size in aluminum transition-metal bilayers. <i>Journal of Applied Physics</i> , 2004, 96, 7278-7282.	1.1	9
129	Summary of ISO/TC 201 Technical Report: ISO/TR 19319: 2003 "Surface chemical analysis" Auger electron spectroscopy and x-ray photoelectron spectroscopy "Determination of lateral resolution, analysis area and sample area viewed by the analyser. <i>Surface and Interface Analysis</i> , 2004, 36, 666-667.	0.8	9
130	Inelastic Mean Free Paths, Mean Escape Depths, Information Depths, and Effective Attenuation Lengths for Hard X-ray Photoelectron Spectroscopy. <i>Springer Series in Surface Sciences</i> , 2016, , 111-140.	0.3	9
131	Quantitative analysis of trace levels of surface contamination by X-ray photoelectron spectroscopy. Part II: Systematic uncertainties and absolute quantification. <i>Surface and Interface Analysis</i> , 2017, 49, 1214-1224.	0.8	9
132	New correlation effects observed for inner-shell excitations in titanium and vanadium. <i>Physical Review Letters</i> , 1987, 58, 507-510.	2.9	8
133	Activities of ISO technical committee 201 on surface chemical analysis. <i>Surface and Interface Analysis</i> , 1994, 21, 615-620.	0.8	8
134	Use of the Bethe equation for inner-shell ionization by electron impact. <i>Journal of Applied Physics</i> , 2016, 119, .	1.1	8
135	X-ray photoemission spectroscopy of environmental particles. <i>Environmental Science & Technology</i> , 1984, 18, 58-61.	4.6	7
136	Simulation of parallel angle-resolved X-ray photoelectron spectroscopy data. <i>Surface and Interface Analysis</i> , 2010, 42, 1072-1075.	0.8	7
137	Quantitative analysis of trace levels of surface contamination by X-ray photoelectron spectroscopy. Part I: Statistical uncertainty near the detection limit. <i>Surface and Interface Analysis</i> , 2017, 49, 1187-1205.	0.8	7
138	Validity of Inelastic-Electron-Scattering Data in Determining the Metallic or Insulating Properties of Adsorbed Atomic Layers. <i>Physical Review B</i> , 1970, 1, 4191-4192.	1.1	6
139	Simulated photoelectron intensities at the aqueous solution "air interface for flat and cylindrical (microjet) geometries. <i>Physical Chemistry Chemical Physics</i> , 2017, 19, 6330-6333.	1.3	6
140	Summary of ISO/TC 201 standards: introduction. <i>Surface and Interface Analysis</i> , 1999, 27, 691-692.	0.8	5
141	Effective attenuation length dependence on photoelectron kinetic energy for gold from 1 keV to 10 keV: Role of island growth in overlayer experiments. <i>Journal of Electron Spectroscopy and Related Phenomena</i> , 2019, 236, 27-32.	0.8	5
142	Summary Abstract: Comparison of L3 shell excitation energies of 3d transition metals obtained by XPS, AEAPS, and EELS. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1984, 2, 840-841.	0.9	4
143	Evaluation of uncertainties in X-ray photoelectron spectroscopy intensities associated with different methods and procedures for background subtraction. II. Spectra for unmonochromated Al and Mg X-rays. <i>Surface and Interface Analysis</i> , 2009, 41, 804-813.	0.8	4
144	Practical formulas for inner-shell ionization cross sections by electron impact: Applications in quantitative Auger electron spectroscopy. <i>Journal of Applied Physics</i> , 2009, 106, 053706.	1.1	4

#	ARTICLE	IF	CITATIONS
145	Photoelectron angular distributions of Cu, Ag, Pt and Au samples: experiments and simulations. <i>Surface and Interface Analysis</i> , 2011, 43, 934-939.	0.8	4
146	Sample-morphology effects on x-ray photoelectron peak intensities. III. Simulated spectra of model core-shell nanoparticles. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2015, 33, .	0.9	4
147	Martin Seah: An extraordinary scientist and metrologist. <i>Surface and Interface Analysis</i> , 2022, 54, 285-293.	0.8	4
148	Applications of the National Institute of Standards and Technology (NIST) database for the simulation of electron spectra for surface analysis for quantitative x-ray photoelectron spectroscopy of nanostructures. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2021, 39, 063205.	0.9	4
149	Report on the 42nd IUVSTA workshop "Electron scattering in solids: from fundamental concepts to practical applications". <i>Surface and Interface Analysis</i> , 2006, 38, 88-117.	0.8	3
150	Electron inelastic mean free paths in compounds. <i>Journal of Surface Analysis (Online)</i> , 2019, 26, 106-107.	0.1	3
151	Semiautomated Data Recording and Control System for an Electron Energy Analyzer. <i>Review of Scientific Instruments</i> , 1973, 44, 1031-1033.	0.6	2
152	Surface analysis by electron spectroscopy at high pressures. <i>Journal of Vacuum Science and Technology</i> , 1978, 15, 549-552.	1.9	2
153	Measurement of silicon dioxide film thicknesses by X-ray photoelectron spectroscopy. <i>AIP Conference Proceedings</i> , 2001, , .	0.3	2
154	Dependence of electron inelastic mean free paths on electron energy and materials at low energy region. I: Elements.. <i>Shinku/Journal of the Vacuum Society of Japan</i> , 1990, 33, 58-62.	0.2	2
155	Origin of exchange decoupling effects in high-coercivity air-annealed CoPd multilayers. <i>Journal of Applied Physics</i> , 2005, 97, 10J104.	1.1	1
156	Interlaboratory study comparing analyses of simulated angle-resolved X-ray photoelectron spectroscopy data. <i>Surface and Interface Analysis</i> , 2014, 46, 321-332.	0.8	1
157	Evaluation of electron inelastic mean free paths for selected elements and compounds. , 2000, 29, 108.		1
158	Electron Inelastic Mean Free Paths in Organic Materials Especially for Polyethylene and Guanine.. <i>Hyomen Kagaku</i> , 1994, 15, 175-180.	0.0	0
159	Summary of the panel discussion on opportunities and needs. <i>Surface and Interface Analysis</i> , 2005, 37, 1072-1074.	0.8	0